


	<h2 style="color: red;">FQP19N10</h2>
	Hersteller-Teilenummer: FQP19N10
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 100V 19A TO-220
	Datenblätter: <ul style="list-style-type: none">  1.FQP19N10.pdf  2.FQP19N10.pdf
	RoHS Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 23582 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP19N10
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 19A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	23582 pcs Stock
detaillierte Beschreibung	N-Channel 100V 19A (Tc) 75W (Tc) Through Hole TO-
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	75W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Tc)
Rds On (Max) @ Id, Vgs	100 mOhm @ 9.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	780pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQP19N10 ist neu im Original, Suche FQP19N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP19N10 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP19N10: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP19N20 Fairchild/ON Semiconductor MOSFET N-CH 200V 19.4A TO-220</p>	 <p>FQP19N20C AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p>FQP18N50PV2 Fairchild/ON Semiconductor FQP18N50PV2 FAIRCHILD</p>	 <p>FQP18N50V2 Fairchild/ON Semiconductor MOSFET N-CH 500V 18A TO-220</p>
 <p>FQP19N20 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19.4A TO-220</p>	 <p>FQP18N50V2 PV2 18N50 FSC FQP18N50V2 PV2 18N50 FSC</p>	 <p>FQP19N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 19A TO-220</p>	 <p>FQP19N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 19A TO-220</p>

heiße Teile

Mehr

 FQP15N60	 FQP15N65	 FQP15N80	 D FQP15P12	 FQP15P12
 FQP16N15	 FQP16N15	 D FQP16N25	 FQP16N25	 FQP16N25C
 FQP16N25C	 FQP17N08	 FQP17N08	 FQP17N08L	 FQP17N08L
 D FQP17N40	 FQP17N40	 FQP17P06	 FQP17P06	 FQP17P10
 FQP17P10	 FQP18N20V2	 FQP18N20V2	 FQP18N50V2	 FQP18N50V2
 FQP19N10	 FQP19N10L	 D FQP19N10L	 FQP19N20	 FQP19N20
 FQP19N20C	 D FQP19N20C	 FQP19N20L	 FQP19N20L	 FQP1N60C
 FQP20N06	 FQP20N06	 FQP20N06L	 FQP20N06L	 FQP20N06TSTU
 FQP20N06TSTU	 FQP20N60	 FQP22N30	 D FQP22N30	 FQP22P10
 FQP22P10	 FQP24N08	 FQP24N08	 FQP24N40	 FQP27N25

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited